



BCT3220

4 Channel Common-Anode LED Driver with Digital Pulse Brightness Control

GENERAL DESCRIPTION

The BCT3220 is a high performance white LED driver. The BCT3220 uses an internal resistor to set the bias current for four LEDs, which are matched to 1.5%. The BCT3220's advantages over ballast resistors include much lower bias variation with supply voltage variation, significantly lower dropout voltage, and in some applications, significantly improved efficiency. The BCT3220 requires only a 50mV dropout voltage at a 20mA load on each output to match the LED brightness.

Users can easily configure the LED current from 2.5mA to 20mA by a serial pulse. The Dimming of white LEDs current can be achieved by applying a pulse signal to the EN pin. There are totally 8 steps of current could be set by users. Internal soft start circuitry effectively reduces the in-rush current while both start-up and mode transition.

FEATURES

- ♦ Low 50mV Dropout at 20mA
- ♦ 20mA full scale current
- ♦ 1.5% LED Current Matching (TYP)
- ♦ One Wire interface for 8-Step Brightness Control
- ♦ 2.7V to 5.5V Supply Voltage Range
- ◆ Thermal Shutdown Protection
- ♦ Low Input Noise and EMI
- ◆ RoHS Compliant and 100% Lead (Pb)-Free, DFN2x2-8L Package

APPLICATIONS

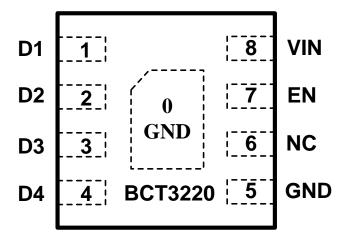
Cell Phones
PDAs
Digital Cameras, Camcorders
Portable Instrumentation
Battery Powered Equipment

ORDERING INFORMATION

С	Order Number Package Type		Temperature Range	Marking	QTY/Reel
ВС	BCT3220ELA-TR DFN2x2-8L		-40°C to +85°C	3220	3000



PIN CONFIGURATION (Top View)



DFN2x2-8L Package

PIN DESCRIPTION

PIN	NAME	FUNCTION	
1	D1	LED Pin1, leave it NC if unused.	
2	D2	LED Pin2, leave it NC if unused.	
3	D3	LED Pin3, leave it NC if unused.	
4	D4	LED Pin4, leave it NC if unused.	
5	GND	Ground	
6	NC	No Connect	
7	EN	Chip Enable (Active High), and connects to GPIO pin of MCU.	
8	VIN	Input voltage	
0	GND	Ground	



TYPICAL APPLICATION CIRCUIT

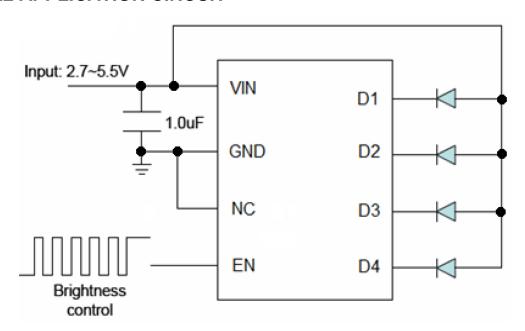


Figure 1: Application Circuit

ABSOLUTE MAXIMUM RATINGS

VIN to GND	0.3V to 6V
All Other Pins to GND	0.3V to (VCC + 0.3V)
Continuous Current (D1- D4)	±30mA
Continuous Power Dissipation (TA = +70°C) 8-Pin DFN (derate 10.5mW/	°C above +70°C)0.84W
Operating Temperature Range	40°C to +85°C
Storage Temperature Range	65°C to +150°C
Junction Temperature	+150°C
Lead Temperature (soldering, 10s)	+260°C
ESD HBM(human body model)	±4KV

NOTE:

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



ELECTRICAL CHARACTERISTICS

(VIN = 2.7V to 5.5V, TA = -40° C to $+85^{\circ}$ C, unless otherwise noted. Typical values are at VIN = 3.3V, TA = $+25^{\circ}$ C.)

PARAMETER	SYM	CONDITIONS	MIN	TYP	MAX	UNITS
POWER SUPPLY			_			
Supply Voltage Range	V_{IN}		2.7		5.5	V
Supply Current	I _{VIN}	V _{IN} = 3.6V, EN=HIGH		150	200	uA
Shut Down Current	I _{SHUT}	EN=LOW			1	uA
Analog Outputs (D1-D4)						
Drop Out Voltage	V_{DROP}	ID_ = 20mA, VD GND		55	75	mV
Current Accuracy	I_D		18	20	22	mA
Current Matching Between Channels	$\triangle I_D$			1.5	3	%
Logic Inputs (EN)						
Input-Logic High	V_{IH}		1.4			V
Input-Logic Low	V_{IL}				0.4	V
Input Leakage Current	I _{IN}	V _{EN} = 0 or V _{IN}	-1		1	uA
IC junction thermal shutdown threshold	TJ-TH			155		οС

NOTES: Devices are 100% tested at TA = \pm 25°C. Limits across the full temperature range are guaranteed by design and correlation.



Brightness Control by Pulse Dimming

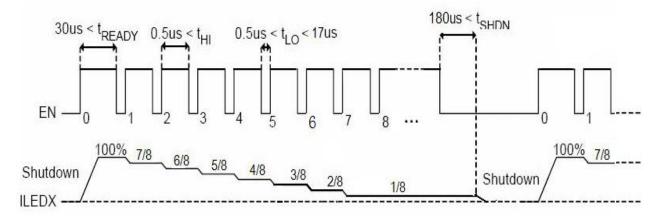


Figure 2: Brightness Control by Pulse Dimming

Number of Pulse Falling Edge	I_DX (mA)
0	20
1	17.5
2	15
3	12.5
4	10
5	7.5
6	5
7	2.5

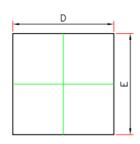
Table 1: Current Setting



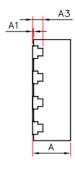
BCT3220 4 Channel Common-Anode LED Driver

With Digital Pulse Brightness Control

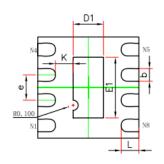
PACKAGE OUTLINE DIMENSIONS



TOP VIEW



SIDE VIEW



BOTTOM VIEW

Symbol	Dimensions Ir	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	0.700	0.800	0.028	0.031	
A1	0.000	0.050	0.000	0.002	
A3	0.203REF.		0.008REF.		
D	1.900	2.100	0.075	0.083	
E	1.900	2.100	0.075	0.083	
D1	0.500	0.700	0.020	0.028	
E1	1.100	1.300	0.043	0.051	
k	0.350REF.		0.014REF.		
b	0.200	0.300	0.008	0.012	
е	0.500BSC.		0.020BSC.		
L	0.274	0.426	0.011	0.017	

DFN2x2-8L

单击下面可查看定价,库存,交付和生命周期等信息

>>Broadchip(广芯电子)